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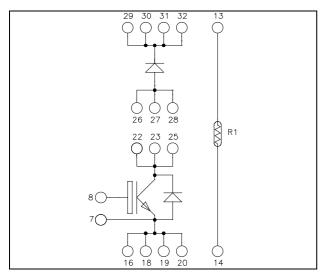


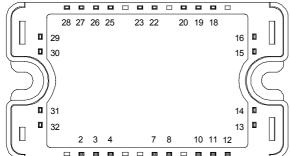




Boost chopper Trench + Field Stop IGBT3 Power Module

 $V_{CES} = 600V$ $I_{C} = 200A$ @ Tc = 100°C





Pins 29/30/31/32 must be shorted together Pins 26/27/28/22/23/25 must be shorted together to achieve a phase leg Pins 16/18/19/20 must be shorted together

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Kelvin emitter for easy drive
- Internal thermistor for temperature monitoring
- High level of integration
- AlN substrate for improved thermal performance

Benefits

- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit	
V_{CES}	Collector - Emitter Breakdown Voltage	600	V	
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	290	
1 _C	I _C Continuous Collector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	200	A
I_{CM}	Pulsed Collector Current $T_C = 25$ °C		400	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	750	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	400A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μA
V _{CE(sat)}	Collector Emitter Saturation Voltage			1.5	1.9	V	
	Collector Emitter Saturation Voltage			1.7		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	ī	Min	Typ	Max	Unit	
Cies	Input Capacitance	$V_{GE} = 0V$			12.3		nF	
C_{oes}	Output Capacitance	$V_{CE} = 25V$			0.8			
C_{res}	Reverse Transfer Capacitance	f = 1MHz			0.4			
Q_{G}	Gate charge	$V_{GE} = \pm 15V ; V_{GE} = 15V ; V_$	$V_{GE} = \pm 15V$; $V_{CE} = 300V$ $I_{C} = 200A$		2.2		μС	
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	hing (25°C)		115		ns	
T_{r}	Rise Time	$V_{GE} = \pm 15V$			45			
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 200A$			225			
$T_{\rm f}$	Fall Time	$R_G = 2\Omega$			55			
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (150°C)		130			
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			50		ns	
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 200A$			300			
T_{f}	Fall Time	$R_G = 2\Omega$			70			
Eon	Turn on Energy	$V_{GE} = \pm 15V$	$T_j = 25^{\circ}C$		1		mJ	
Lon	Turn on Energy	$V_{\text{Bus}} = 300V$	$T_j = 150$ °C		1.8			
Б	Turn off Energy	$I_C = 200A$ $R_G = 2\Omega$	1 -		5.7	5.7		m I
E_{off}	Turn off Energy		$T_j = 150$ °C		7		mJ	
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; V_{Bu} $t_p \le 6\mu s$; $T_j = 15$			1000		A	

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_i = 25$ °C $T_i = 150$ °C			250 500	μΑ
I_{F}	DC Forward Current		$T_j = 150^{\circ}C$ $T_c = 80^{\circ}C$		200	300	A
V	$I_F = 200A$	$T_i = 25^{\circ}C$		1.6	2	V	
V_{F}	Diode Forward Voltage	$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		v
t_{rr}	Reverse Recovery Time	T _j :	$T_j = 25^{\circ}C$		125		ns
·rr	Reverse Recovery Time		$T_j = 150$ °C		220		113
Qrr	Reverse Recovery Charge	$I_F = 200A$ $V_R = 300V$ $di/dt = 2800A/\mu s$	$T_j = 25^{\circ}C$		9		μС
Qrr	Reverse Recovery Charge			$T_{i} = 150^{\circ}C$		20	
E.,	Payarga Pagayary Engray		$T_j = 25^{\circ}C$		2.2		mJ
EI	Er Reverse Recovery Energy		$T_{j} = 150^{\circ}C$		4.8		111J



Thermal and package characteristics

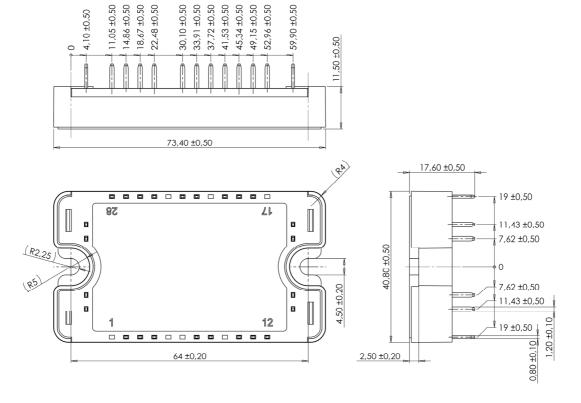
Symbol	Characteristic			Min	Тур	Max	Unit
D	Junction to Case Thermal Resistance		IGBT			0.20	°C/W
R_{thJC}			Diode			0.31	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		175	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					110	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic			Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C				50		kΩ
$\Delta R_{25}/R_2$					5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$				3952		K
$\Delta \mathrm{B/B}$			T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \begin{array}{l} \text{T: Thermistor temperature} \\ R_T: \text{ Thermistor value at T} \end{array}$$

SP3 Package outline (dimensions in mm)

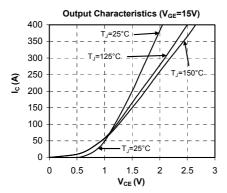


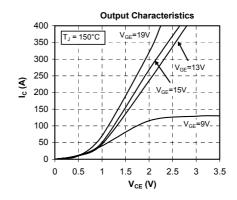
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

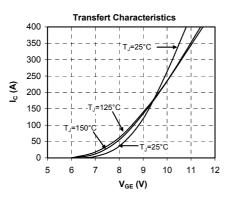
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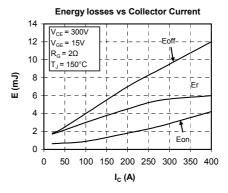


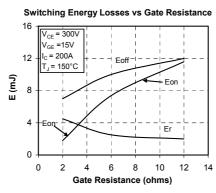
Typical Performance Curve

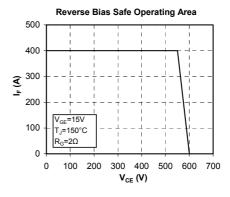


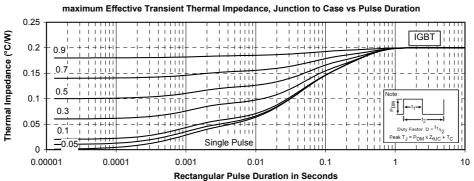




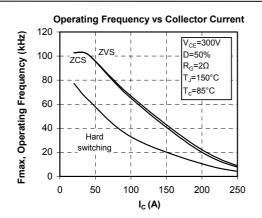


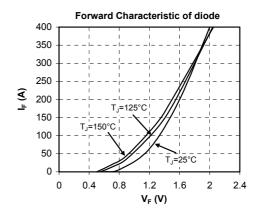


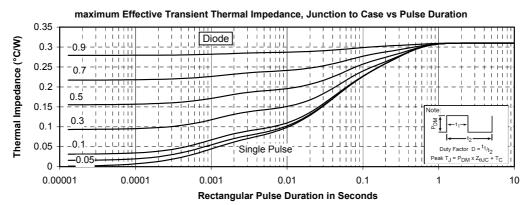












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